

Revision 0.91

# SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



## General Product Information

Product	Application
785 nm DFB Laser	Raman Spectroscopy
with hermetic TO Package (RoHS compliant)	Metrology
including Monitor Diode	Interferometry



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T <sub>S</sub>	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-20		75
Operational Temperature at Laser Chip	$T_LD$	°C	0		50
Forward Current	I <sub>F</sub>	mA			190
Reverse Voltage	$V_R$	V			2
Output Power	$P_{\text{opt}}$	mW			110
TEC Current	$I_{TEC}$	Α			1.0
TEC Voltage	$V_{TEC}$	V			1.0

#### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

## Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	15		40
Forward Current	I <sub>F</sub>	mA			170
Output Power	P <sub>opt</sub>	mW	20		100

Measurement Conditions / Comments
measured with integrating sphere

## Characteristics at T<sub>LD</sub> = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	784	785	786
Linewidth (FWHM)	Δλ	MHz		2	
Sidemode Supression Ratio	SMSR	dB		50	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dI	nm / mA		0.003	

Measurement Conditions / Comments	
$P_{opt} = 100 \text{ mW}$	
$P_{opt} = 100 \text{ mW}$	

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This data sheet is subject to change without notice.

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Characteristics at T <sub>LD</sub> = 25° C	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Laser Current @ P <sub>opt</sub> = 100 mW	I <sub>LD</sub>	mA			170
Slope Efficiency	η	W/A	0.6	0.8	1.4
Threshold Current	I <sub>th</sub>	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	0		5	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		18	
Degree of Polarization	DOP	%		80	

Measurement Conditions / Comments
Measurement Conditions / Comments
parallel to Pin 1 - Pin 6 plane (see p. 3)
perpendicular to Pin 1 - Pin 6 plane (see p. 3)
P <sub>opt</sub> = 100 mW; E field perpendicular to Pin 1 - 6 plane

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>opt</sub>	μA/mW	1	t.b.d.	100
. ,	'				

Measi	rement Conditions / Comments
$J_R =$	5 V

Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		0.4	
Voltage	$U_TEC$	V		0.4	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.4	
Temperature Difference	ΔΤ	K			40

Meası	urement Conditions / Comments	
P <sub>opt</sub> =	100 mW, ΔT = 20 K	
P <sub>opt</sub> =	100 mW, $\Delta T = 20 \text{ K}$	
P <sub>opt</sub> =	100 mW, $\Delta T = 20 \text{ K}$	
P <sub>opt</sub> =	100 mW, $\Delta T =  Tcase - TLD $	

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3930	
Steinhart & Hart Coefficient A	А		1.029 x 10 <sup>-3</sup>		
Steinhart & Hart Coefficient B	В		2.510 x 10 <sup>-4</sup>		
Steinhart & Hart Coefficient C	C			1.051 x 10	-7

Measurement Conditions / Comments						
$T_{LD} = 25^{\circ} C$						
$R_1/R_2=e^{\beta(1/T_1-1/T_2)}$ at $T_{LD}=$	0° 50° C					
$1/T = A + B(\ln R) + C(\ln R)^3$						
T: temperature in Kelvin						
R: resistance at T in Ohm						

Thermistor (Standard NTC Type)

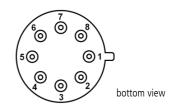


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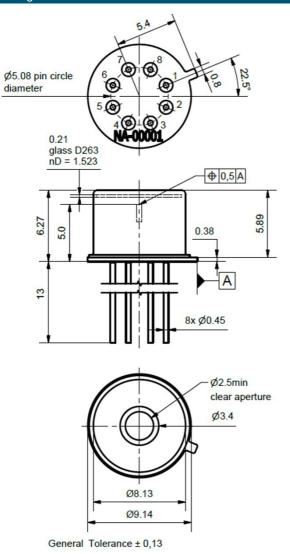
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Pin Assignment							
1	Laser Diode Anode	5	Thermistor				
2	Laser Diode Cathode	6	Thermistor				
3	Thermoelectric Cooler (-)	7	Photo Diode Anode				
4	Thermoelectric Cooler (+)	8	Photo Diode Cathode				
All 8 pins are isolated from case.							



## Package Drawings



AIZ-19-0129-1426B



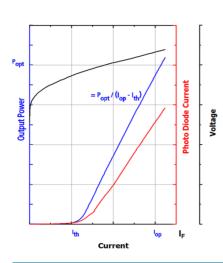
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## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

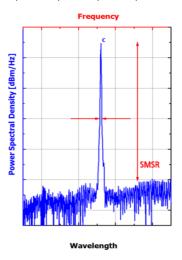


#### Typical Measurement Results

Output Power vs. Current



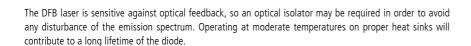
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 785 nm
MAX. OUTPUT POWER 110 mW



